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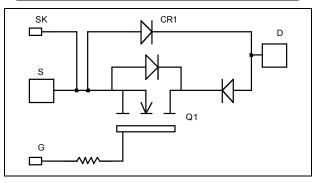
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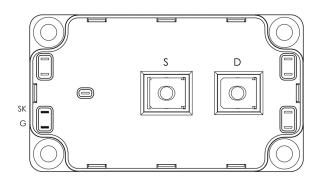
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Single switch Series & parallel diodes MOSFET Power Module





APTM50UM13SAG

 $V_{DSS} = 500V$ $R_{DSon} = 13m\Omega \text{ typ } @ \text{ Tj} = 25^{\circ}C$ $I_{D} = 335A @ \text{ Tc} = 25^{\circ}C$

Application

- Welding converters
 - Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Power MOS 7[®] MOSFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Avalanche energy rated
 - Very rugged
 - Kelvin source for easy drive
 - Very low stray inductance
 - Symmetrical design
 - M5 power connectors
 - High level of integration
 - AlN substrate for improved thermal performance

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant

All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V _{DSS}	Drain - Source Breakdown Voltage		500	V
т	Continuous Drain Current	$T_c = 25^{\circ}C$	335	
I _D	Continuous Drain Current	$T_c = 80^{\circ}C$	250	А
I _{DM}	Pulsed Drain current		1340	
V _{GS}	Gate - Source Voltage		±30	V
R _{DSon}	Drain - Source ON Resistance		15	mΩ
PD	Maximum Power Dissipation $T_c = 25^{\circ}C$		3290	W
I _{AR}	Avalanche current (repetitive and non repetitive)		71	А
E _{AR}	Repetitive Avalanche Energy		50	mI
E _{AS}	Single Pulse Avalanche Energy		3000	mJ

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
I _{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 500V$			400	μA
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 167.5A$		13	15	mΩ
V _{GS(th)}	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 20 \text{mA}$	3		5	V
I _{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$			±300	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
C _{iss}	Input Capacitance	$V_{GS} = 0V$		42.2		
C _{oss}	Output Capacitance	$V_{\rm DS} = 25 V$		8.24		nF
C _{rss}	Reverse Transfer Capacitance	f = 1MHz		0.42		
Qg	Total gate Charge	$V_{GS} = 10V$		800		
Q _{gs}	Gate – Source Charge	$V_{Bus} = 250V$		200		nC
Q_{gd}	Gate – Drain Charge	I _D =335A		420		
T _{d(on)}	Turn-on Delay Time	Inductive switching @ 125°C		21		
Tr	Rise Time	$V_{GS} = 15V$		42		ns
T _{d(off)}	Turn-off Delay Time	$V_{Bus} = 333V$ $I_D = 335A$		96		
$T_{\rm f}$	Fall Time	$R_G = 0.8\Omega$		100		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C		4		T
$\mathrm{E}_{\mathrm{off}}$	Turn-off Switching Energy	- V _{GS} = 15V, V _{Bus} = 333V I _D = 335A, R _G = 0.8Ω		4.16		mJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C $V_{GS} = 15V, V_{Bus} = 333V$ $I_D = 335A, R_G = 0.8\Omega$		6.32		mI
$\mathrm{E}_{\mathrm{off}}$	Turn-off Switching Energy			4.64		mJ
R _{thJC}	Junction to Case Thermal Resistan	ice			0.038	°C/W

Series diode ratings and characteristics

Symbol	Characteristic	cteristic Test Conditions		Min	Тур	Max	Unit
V _{RRM}	Maximum Peak Repetitive Reverse Vol	tage		600			V
I _{RM}	Maximum Reverse Leakage Current	V _R =600V				150	μA
I _F	DC Forward Current		$T_c = 80^{\circ}C$		360		А
	Diode Forward Voltage	$I_{\rm F} = 360 {\rm A}$			1.7	2.5	
V _F		$I_F = 720A$			2		V
		$I_{\rm F} = 360 {\rm A}$	$T_{i} = 125^{\circ}C$		1.4		
+	t_{rr} Reverse Recovery Time $I_F = 360A$		$T_j = 25^{\circ}C$		70		
ι _{rr}		$T_{j} = 125^{\circ}C$		140		ns	
0	Reverse Recovery Charge	$V_{R} = 400V$ di/dt = 1200A/µs	$T_j = 25^{\circ}C$	0.6		чС	
Q _{rr}			$T_{j} = 125^{\circ}C$		4.2		μC
R _{thJC}	Junction to Case Thermal Resistance					0.16	°C/W

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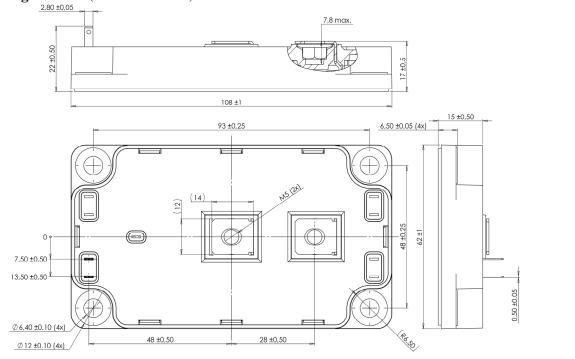
Parallel diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V _{RRM}	Maximum Peak Repetitive Reverse Vol	tage	600			V	
I _{RM}	Maximum Reverse Leakage Current	$V_{R} = 600 V$				150	μA
I _F	DC Forward Current		$T_c = 80^{\circ}C$		360		Α
		$I_{\rm F} = 360 {\rm A}$			1.7	2.5	V
V _F	Diode Forward Voltage	$I_F = 720A$			2		
		$I_{\rm F} = 360 {\rm A}$	$T_{i} = 125^{\circ}C$		1.4		
4	Reverse Recovery Time		$T_j = 25^{\circ}C$		70		
t _{rr}		$I_{\rm F} = 360 {\rm A}$	$T_{i} = 125^{\circ}C$		140		ns
0	Reverse Recovery Charge	$V_R = 400V$ di/dt = 1200A/µs	$T_j = 25^{\circ}C$		0.6		C
Q _{rr}			$T_{j} = 125^{\circ}C$		4.2		μC
R _{thJC}	Junction to Case Thermal Resistance					0.16	°C/W

Thermal and package characteristics

Symbol	Characteristic			Min	Max	Unit				
V _{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000		V				
T _J	Operating junction temperature range		-40	150						
T _{JOP}	Recommended junction temperature under	switching conditio	ns	-40	T _J max -25	max -25 °C				
T _{STG}	Storage Temperature Range	ture Range -40 125								
T _C	Operating Case Temperature	-40	100							
Torqua	Mounting tongue	To heatsink	M6	3	5	N.m				
Torque	Mounting torque For terminals M5		M5	2	3.5	IN.III				
Wt	Package Weight				300	g				

SP6 Package outline (dimensions in mm)

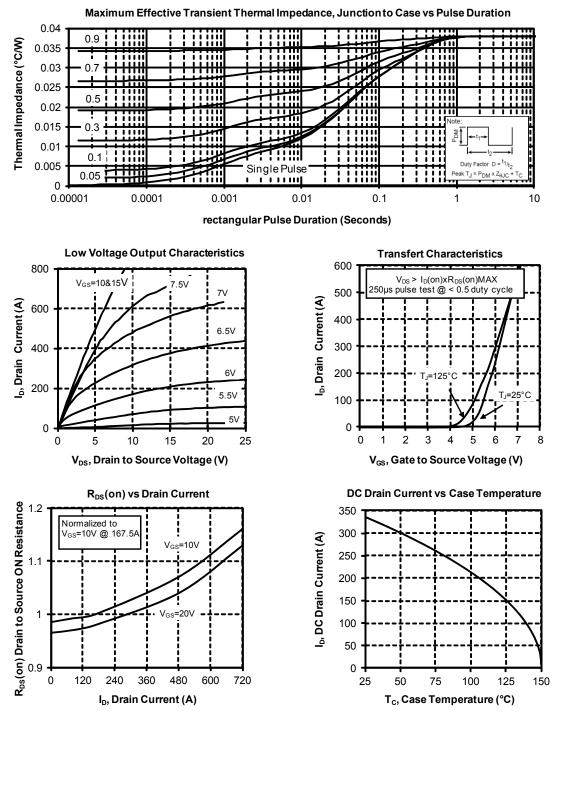


See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

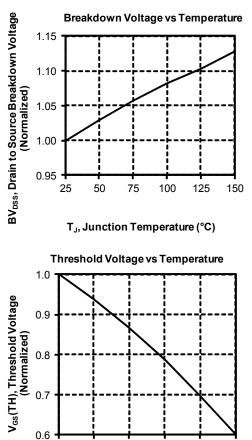
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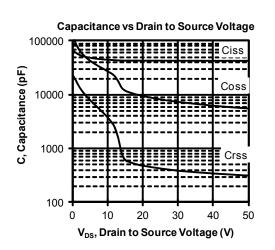


Typical Performance Curve









75

T_c, Case Temperature (°C)

100

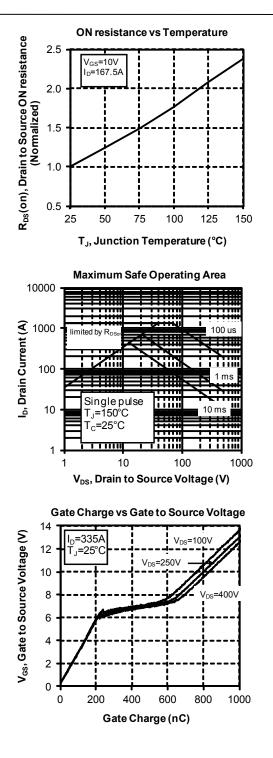
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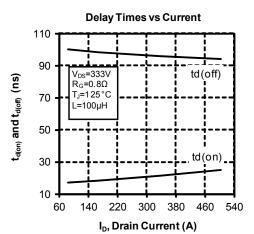
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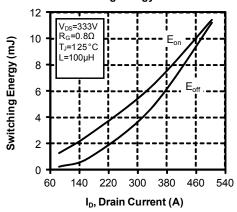
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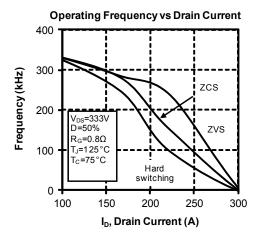


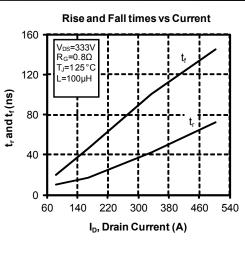




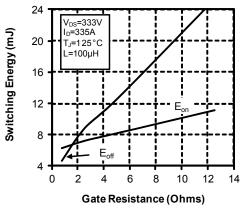
Switching Energy vs Current

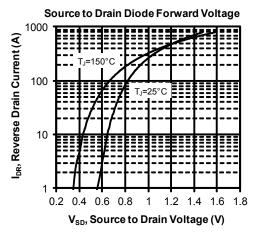






Switching Energy vs Gate Resistance







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